

VUDA003R80APA

Datasheet

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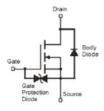


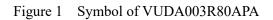
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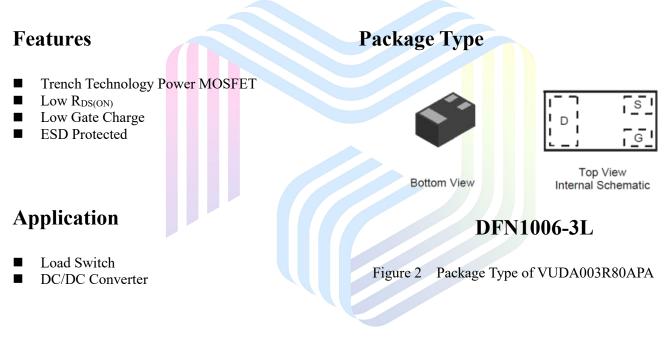
General Description

V _{(BR)DSS}	R _{DS(ON)_max}	I _D
-30V	800mΩ@-10V	0.45 A
	900mΩ@-4.5V	-0.45A









Ordering Information

Product Name	Package
VUDA003R80APA	DFN1006-3L



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Absolute Maximum Ratings (T_A= 25 °C, unless otherwise specified)

Parameter	Symbol	Rating	Unit	
Drain-Source Voltage	V _{DSS}	-30	V	
Gate-Source Voltage	V _{GSS}	±12	V	
Continuous Drain Current ^{Note1}	ID	-0.45	- A	
Pulsed Drain Current Note2	I _{DM}	-1.8		
Total Power Dissipation ^{Note4}	PD	0.3	W	
Junction Temperature	TJ	150	°C	
Storage Temperature	T _{STG}	-55 to 150	°C	

Thermal Resistance

Parameter	Symbol	Min	Т <mark>у</mark> р	Max	Unit
Thermal Resistance, Junction-to-Ambient ^{Note5}	R _{0JA}		4 <mark>16</mark>		°C/W



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Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Statistic Characteristics							
Drain-Source Breakdown Voltage	BV _{DSS}	$V_{GS}=0V, I_D=250uA$	-30			V	
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} = -30V, V_{GS} =0V			-1	uA	
Gate-Body Leakage Current	I _{GSS}	$V_{GS} = \pm 10V, V_{DS} = 0V$			±5	uA	
Gate Threshold Voltage ^{Note3}	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250uA	-0.5	-1	-1.5	V	
Contraction Contraction Note3	R _{DS(ON)}	V_{GS} =-10V, I_D = -0.3A		470	800	mΩ	
Static Drain-Source On-Resistance ^{Note3}		V_{GS} =-4.5V, I_D = -0.3A		680	900		
Dynamic Characteristics							
Input Capacitance	CISS	V _{DS} =-15V		55.2		pF	
Output Capacitance	Coss	V _{GS} =0V		10.8		pF	
Reverse Transfer Capacitance	C _{RSS}	f=1MHz		7.4		pF	
Total Gate Charge	Qg	V _{DS} =-10V		0.60			
Gate-Source Charge	Qgs	V_{GS} =-4.5V		0.46		nC	
Gate-Drain Charge	Q _{gd}	$I_{D} = -0.5 A$		0.12			
Gate Resistance	Rg	f = 1MHz, Open drain		13.4		Ω	
Switching Parameters							
Turn-on Delay Time	t _{d(on)}	V_{DD} = -10V		8.5			
Turn-on Rise Time	tr	$V_{GS} = -4.5V$		5.8			
Turn-off Delay Time	t _{d(off)}	$R_L=50\Omega$		31		– ns	
Turn-off Fall Time	t _f	$R_{G}=3\Omega$		18			
Diode Characteristics			1	1			
Diode Forward Voltage Note3	V _{SD}	$V_{GS}=0V, I_{S}=-0.3A$			-1.2	V	
Notes :	1		1	1			

Electrical Characteristics (T_J= 25 °C, unless otherwise specified)

Notes :

1. The maximum current rating is limited by package. And device mounted on a large heatsink

2.Pulse Test : Pulse Width $\leq 10\mu s$, duty cycle $\leq 1\%$.

3.Pulse Test : Pulse Width \leq 300µs, duty cycle \leq 2%.

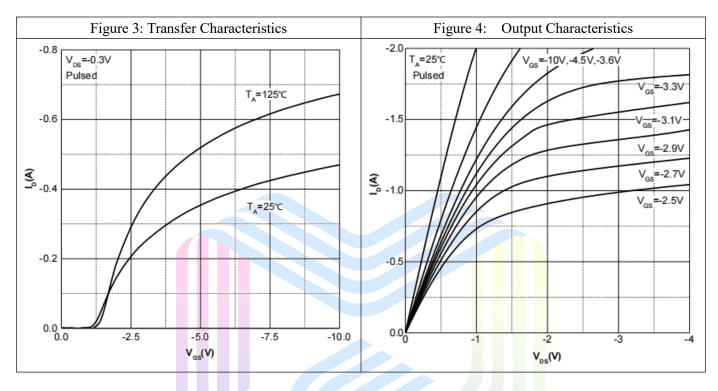
4. The power dissipation P_D is limited by $T_{J(MAX)} = 150^{\circ}C$. And device mounted on a large heatsink

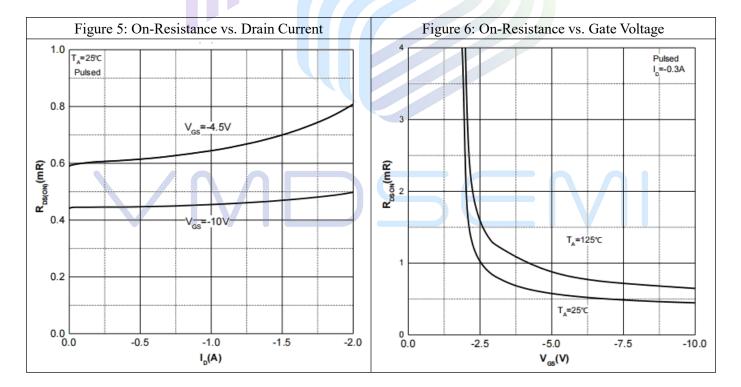
5.Device mounted on $1in^2$ FR-4 board with 2oz Copper, in a still air environment with $T_A = 25^{\circ}C$.



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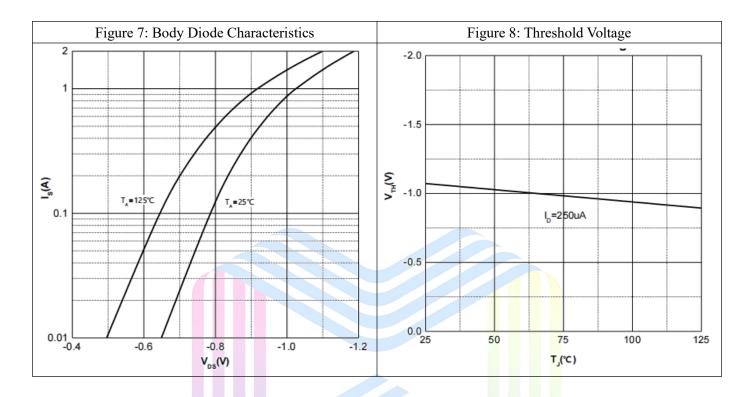
Typical Performance Characteristics







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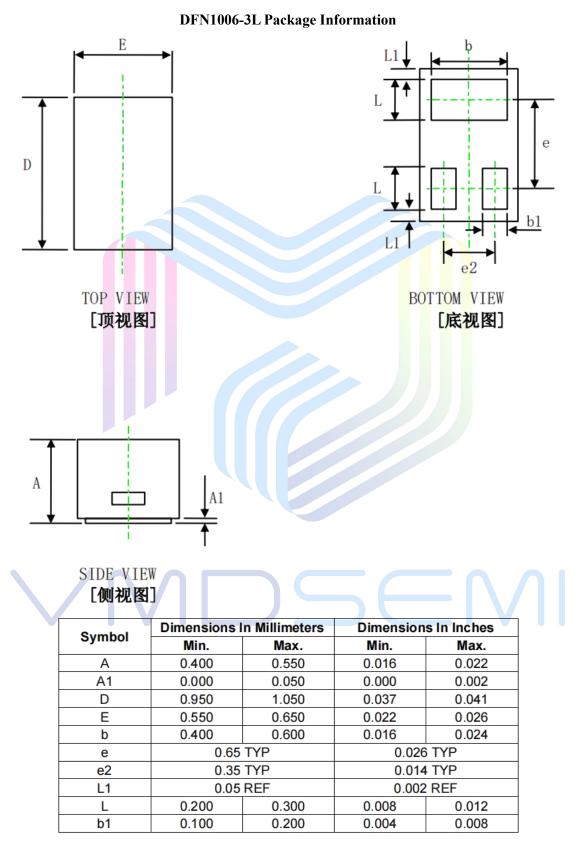


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Mechanical Dimensions:





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